

60 V, 6 A NPN high power bipolar transistor 8 December 2014

Product data sheet

1. General description

NPN high power bipolar transistor in a SOT669 (LFPAK56) Surface-Mounted Device (SMD) power plastic package.

PNP complement: PHPT60606PY

2. Features and benefits

- High thermal power dissipation capability
- High temperature applications up to 175 °C
- Reduced Printed Circuit Board (PCB) requirements comparing to transistors in DPAK
- High energy efficiency due to less heat generation
- AEC-Q101 qualified.

3. Applications

- Power management
- Load switch
- Linear mode voltage regulator
- Backlighting applications
- Relay replacement
- Motor drive

4. Quick reference data

| Table 1. Quick reference data | | | | | | | |
|-------------------------------|--|---|--|-----|-----|-----|------|
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
| V _{CEO} | collector-emitter voltage | open base | | - | - | 60 | V |
| I _C | collector current | | | - | - | 6 | А |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms | | - | - | 14 | А |
| R _{CEsat} | collector-emitter saturation resistance | I_C = 6 A; I_B = 600 mA; pulsed; t_p ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C | | - | 34 | 45 | mΩ |



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5. Pinning information

| Table 2. | Pinning | information | | |
|----------|---------|-------------|--|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | E | emitter | mb | С |
| 2 | E | emitter | | в |
| 3 | E | emitter | a | - h a |
| 4 | В | base | មុច្ចុថ្ | E sym123 |
| mb | С | collector | 1 2 3 4 LFPAK56; Power- SO8 (SOT669) | Syn1125 |

6. Ordering information

| Table 3. Ordering information | | | | | |
|---------------------------------|-----------------------|--|---------|--|--|
| Type number | Package | | | | |
| | Name | Description | Version | | |
| PHPT60606NY | LFPAK56; Power-SO8 | Plastic single-ended surface-mounted package (LFPAK56; Power-SO8); 4 leads | SOT669 | | |

7. Marking

| Table 4. Marking codes | |
|------------------------|--------------|
| Type number | Marking code |
| PHPT60606NY | 0606NAB |

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8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|---------------------------|-------------------------------------|-----|-----|------|------|
| V _{CBO} | collector-base voltage | open emitter | | - | 60 | V |
| V _{CEO} | collector-emitter voltage | open base | | - | 60 | V |
| V _{EBO} | emitter-base voltage | open collector | | - | 7 | V |
| I _C | collector current | | | - | 6 | А |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms | | - | 14 | А |
| I _B | base current | | | - | 800 | mA |
| I _{BM} | peak base current | single pulse; t _p ≤ 1 ms | | - | 1.4 | А |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 1.35 | W |
| | | | [2] | - | 3.25 | W |
| | | | [3] | - | 5 | W |
| | | | [4] | - | 25 | W |
| Tj | junction temperature | | | - | 175 | °C |
| T _{amb} | ambient temperature | | | -55 | 175 | °C |
| T _{stg} | storage temperature | | | -65 | 175 | °C |

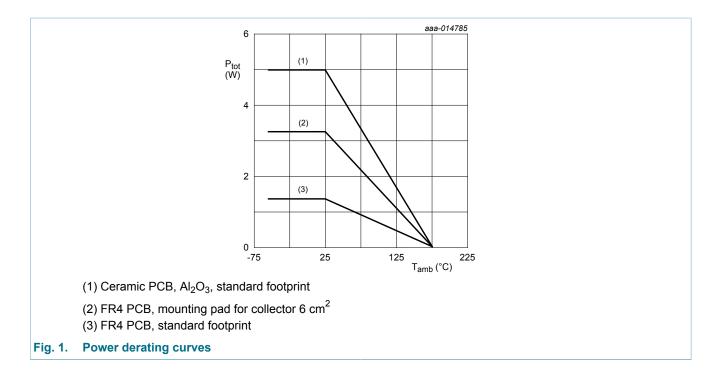
[1] Device mounted on an FR4 Printed-Circuit Board (PCB); single-sided copper; tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB; single-sided copper; tin-plated and mounting pad for collector 6 cm².

[3] Device mounted on a ceramic PCB; AI_2O_3 , standard footprint.

[4] Power dissipation from junction to mounting base.

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9. Thermal characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|--|---|-------------|-----|-----|-----|-----|------|
| R _{th(j-a)} thermal resistance from junction to ambient | | in free air | [1] | - | - | 111 | K/W |
| | | [2] | - | - | 46 | K/W | |
| | ambient | | [3] | - | - | 30 | K/W |
| R _{th(j-mb)} | thermal resistance from junction to mounting base | | | - | - | 6 | K/W |

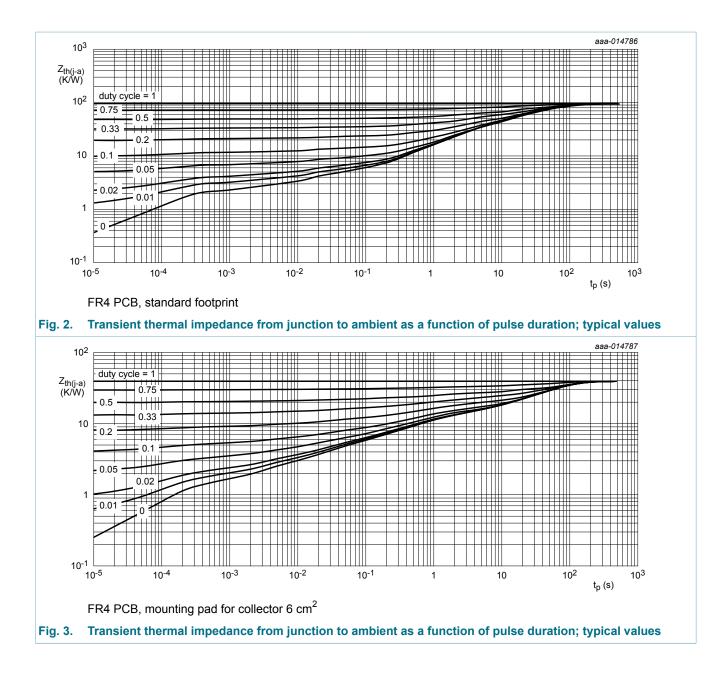
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 6 cm².

[3] Device mounted on a ceramic Printed-Circuit Board (PCB), Al₂O₃, standard footprint.



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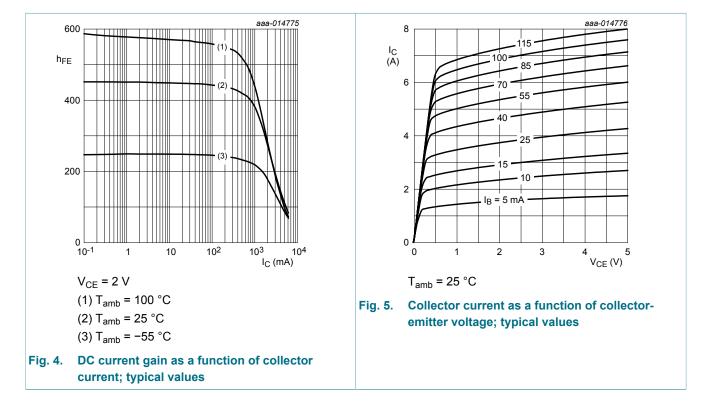
10. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|--------------------|---|--|-----|------|------|------|
| I _{CBO} | collector-base cut-off | V_{CB} = 48 V; I _E = 0 A; T _{amb} = 25 °C | - | - | 100 | nA |
| | current | V_{CB} = 48 V; I _E = 0 A; T _j = 150 °C | - | - | 50 | μA |
| I _{CES} | collector-emitter cut-off current | V_{CE} = 48 V; V_{BE} = 0 V; T_{amb} = 25 °C | - | - | 100 | nA |
| I _{EBO} | emitter-base cut-off current | V_{EB} = 7 V; I _C = 0 A; T _{amb} = 25 °C | - | - | 100 | nA |
| h _{FE} | DC current gain | V_{CE} = 2 V; I _C = 500 mA; T _{amb} = 25 °C | 240 | 390 | - | |
| | | V_{CE} = 2 V; I_C = 1 A; $t_p \le 300 \ \mu$ s; $\delta \le 0.02$; T_{amb} = 25 °C | 210 | 340 | - | |
| | | V_{CE} = 2 V; I_C = 3 A; $t_p \le 300 \ \mu$ s; $\delta \le 0.02$; T_{amb} = 25 °C | 100 | 160 | - | |
| | | $\label{eq:Vce} \begin{split} V_{CE} &= 2 \text{ V}; \text{ I}_{C} = 6 \text{ A}; \text{t}_{p} \leq 300 \mu\text{s}; \\ \delta \leq 0.02; \text{T}_{amb} = 25 ^\circ\text{C}; \text{ pulsed} \end{split}$ | 40 | 70 | - | |
| V _{CEsat} | collector-emitter saturation voltage | I_C = 1 A; I_B = 50 mA; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C; pulsed | - | 50 | 75 | mV |
| | | I_{C} = 3 A; I_{B} = 300 mA; pulsed; $t_{p} \le 300 \ \mu$ s; δ ≤ 0.02; T_{amb} = 25 °C | - | 110 | 160 | mV |
| | | I_{C} = 6 A; I_{B} = 300 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C | - | 240 | 360 | mV |
| R _{CEsat} | collector-emitter saturation resistance | I_{C} = 6 A; I_{B} = 600 mA; pulsed; $t_{p} \le 300 \ \mu$ s; δ ≤ 0.02; T_{amb} = 25 °C | - | 34 | 45 | mΩ |
| V _{BEsat} | base-emitter saturation voltage | I_{C} = 1 A; I_{B} = 50 mA; pulsed; $t_{p} \le 300 \ \mu$ s; δ ≤ 0.02 ; T_{amb} = 25 °C | - | 0.85 | 0.95 | V |
| | | I_{C} = 3 A; I_{B} = 300 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C | - | 1 | 1.15 | V |
| | | I_{C} = 6 A; I_{B} = 300 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C | - | 1.05 | 1.2 | V |
| V _{BEon} | base-emitter turn-on voltage | V_{CE} = 2 V; I _C = 0.5 A; T _{amb} = 25 °C | - | 0.7 | 0.8 | V |
| d | delay time | V_{CC} = 12.5 V; I _C = 3 A; I _{Bon} = 0.15 A; | - | 10 | - | ns |
| r | rise time | I_{Boff} = -0.15 A; T_{amb} = 25 °C | - | 135 | - | ns |
| on | turn-on time | | - | 145 | - | ns |
| ·S | storage time | | - | 465 | - | ns |
| f | fall time | | - | 225 | - | ns |
| t _{off} | turn-off time | | - | 690 | - | ns |

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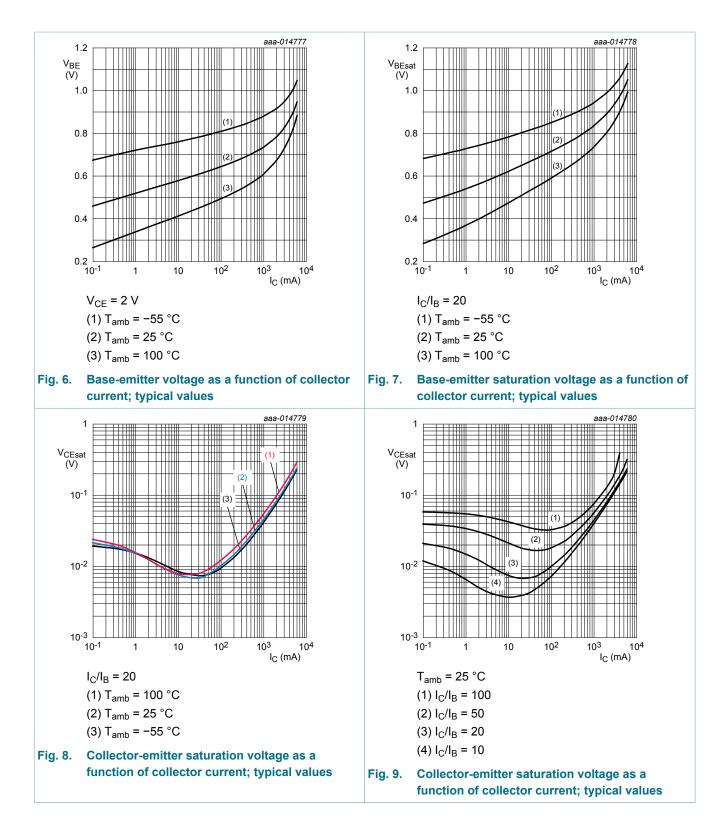
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------|-----------------------|--|-----|-----|-----|------|
| f _T | transition frequency | V_{CE} = 10 V; I _C = 500 mA; f = 100 MHz; T _{amb} = 25 °C | - | 180 | - | MHz |
| C _c | collector capacitance | V _{CB} = 10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C | - | 23 | - | pF |



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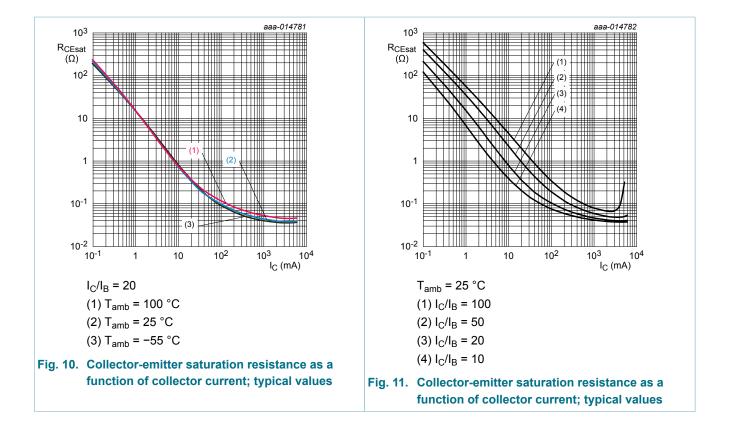
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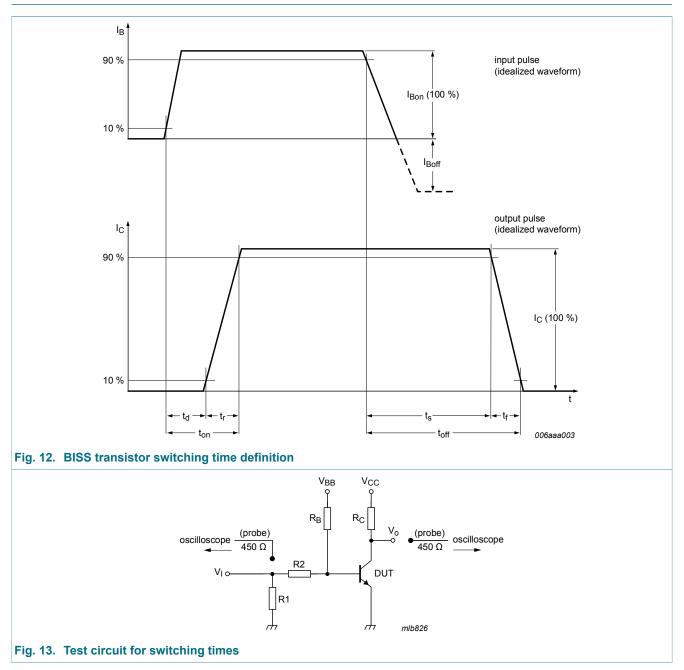
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11. Test information



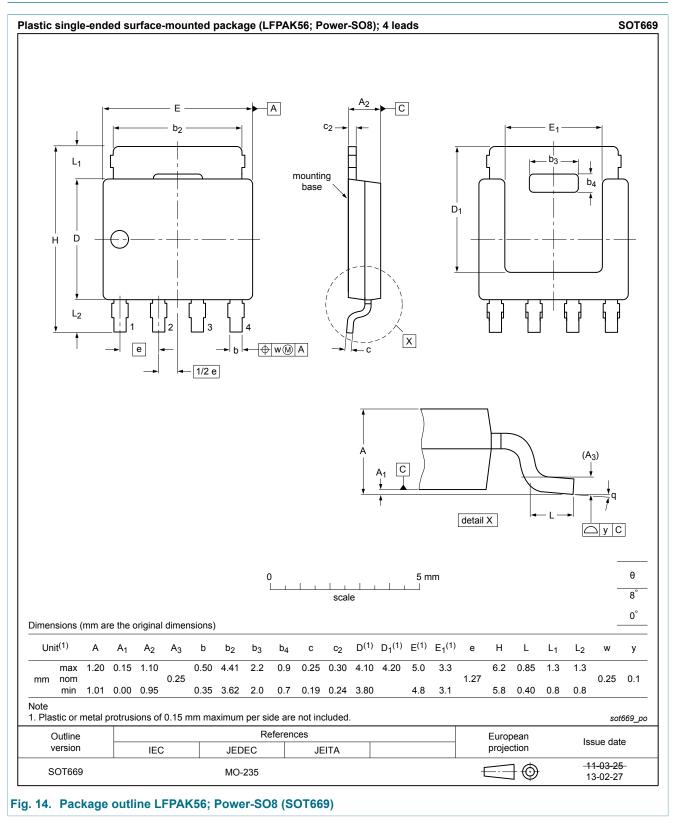
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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12. Package outline



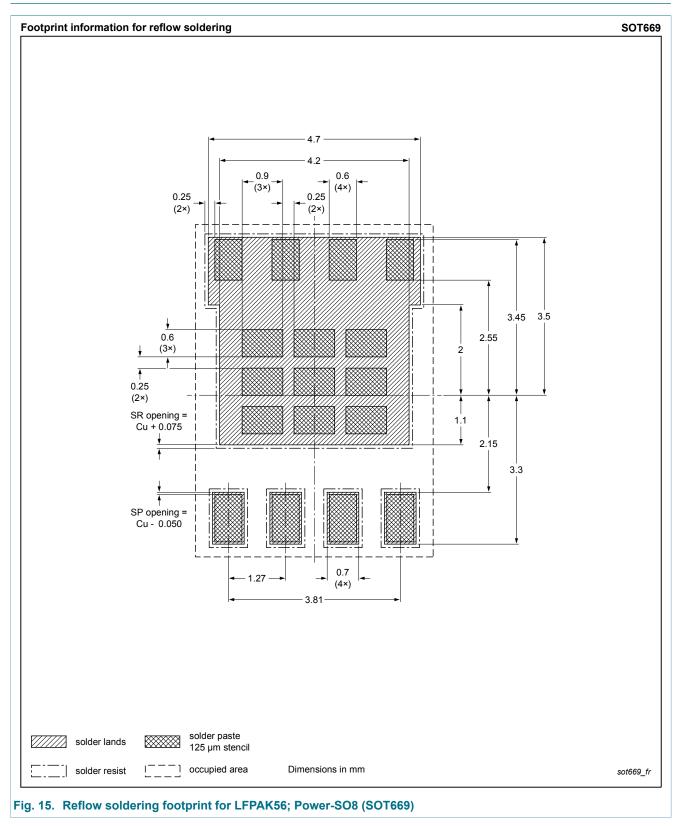
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13. Soldering



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14. Revision history

| Table 8. Revision history | | | | | |
|---------------------------|--------------|--------------------|---------------|------------|--|
| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes | |
| PHPT60606NY v.1 | 20141208 | Product data sheet | - | - | |

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15. Legal information

15.1 Data sheet status

| Document status [1][2] | Product status [<u>3]</u> | Definition |
|--------------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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